



Datasheet

100 V, 2 x 30 A field-effect rectifier diode



Features

- AEC-Q101 qualified
- PPAP capable
- Operating T_i from -40 °C to 175 °C
- ST patented rectifier process
- Stable leakage current over reverse voltage
- Low forward voltage drop
- High frequency operation
- ECOPACK compliant

Applications

- Battery charger
- DC / DC converter
- OBC (on-board battery charger)
- PHEV EV charging station
- Resonant LLC topology
- PFC functions (power factor correction)

Description

The FERD60H100C-Y is based on proprietary technology that achieves the best in class $V_{\text{F}}/I_{\text{R}}$ trade-off for a given silicon surface.

This 100 V automotive diode has been optimized for use in confined applications where both efficiency and thermal performance are key parameters.

This device is suitable to be used in DCDC converter by improving the efficiency.

Product status link	
FERD60H100C-Y	

Product summary			
I _{F(AV)}	2 x 30 A		
V _{RRM}	100 V		
T _j (max.)	175 °C		
V _F (typ.)	0.64 V		



1 Characteristics

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Table 1. Absolute ratings (limiting values per diode at 25 °C , unless otherwise specified)

Symbol		Value	Unit		
V _{RRM}	Repetitive peak reverse voltage	100	V		
I _{F(RMS)}	Forward rms current	60	А		
I-mo	Average ferward ourrent	T = 145 °C δ = 0.5	Per diode	30	^
'F(AV)	F(AV) Average forward current	$T_{\rm C} = 143 {\rm C}, 0 = 0.3$	Per device	60	A
I _{FSM}	Surge non repetitive forward current t _p = 10 ms sinusoidal			290	А
T _{stg}	Storage temperature range	-65 to +175	°C		
Тј	Operating junction temperature	-40 to +175	°C		

Table 2. Thermal resistance parameters

Symbol	Baramatar	Va	Unit		
Symbol	Farameter		Тур.	Max.	Onit
R _{th(j-c)}	Junction to case	Per diode	0.60	1.06	°C/M
		Per device	0.30	0.53	C/VV

For more information, please refer to the following application note:

AN5088: Rectifiers thermal management, handling and mounting recommendations

Symbol	Parameter	Test conditions		Тур.	Max.	Unit
I _R ⁽¹⁾ R	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}		60	μA
		T _j = 125 °C			10	mA
		T _j = 125 °C	V _R = 70 V		5	mA
V _F ⁽²⁾ For	Forward voltage drop	T _j = 25 °C		0.46	0.52	
		T _j = 125 °C	IF - 3 A	0.41	0.45	
		T _j = 25 °C	I _F = 15 A	0.62	0.70	
		T _j = 125 °C		0.56	0.61	V
		T _j = 25 °C	L = 20 A	0.75	0.85	V
		T _j = 125 °C	1F - 30 A	0.64	0.70	
		T _j = 25 °C	1 60.4	0.92		
		T _j = 125 °C	IF - 00 A	0.76		

Table 3. Static electrical characteristics (per diode)

1. Pulse test: $t_p = 5 ms, \delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses, use the following equation: $P = 0.55 \times I_{F(AV)} + 0.005 \times I_{F}^{2} (RMS)$ For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

1.1 **Characteristics (curves)**









C(pF) 10000 1000 | | V_R(V) 100 0.1 1.0 10.0 100.0



Figure 6. Thermal resistance junction to ambient versus copper surface under tab (typical values)



2 Package information

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In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 D²PAK package information

- Epoxy meets UL94, V0.
- Cooling method: by conduction (C)





Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

		Dimensions						
Ref.		Millimeters			Inches (for reference only)			
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А	4.40		4.60	0.173		0.181		
A1	0.03		0.23	0.001		0.009		
b	0.70		0.93	0.028		0.037		
b2	1.14		1.70	0.045		0.067		
С	0.45		0.60	0.018		0.024		
c2	1.23		1.36	0.048		0.053		
D	8.95		9.35	0.352		0.368		
D1	7.50	7.75	8.00	0.295	0.305	0.315		
D2	1.10	1.30	1.50	0.043	0.051	0.060		
E	10.00		10.40	0.394		0.409		
E1	8.30	8.50	8.70	0.335	0.343	0.346		
E2	6.85	7.05	7.25	0.266	0.278	0.282		
е		2.54			0.100			
e1	4.88		5.28	0.190		0.205		
Н	15.00		15.85	0.591		0.624		
J1	2.49		2.69	0.097		0.106		
L	2.29		2.79	0.090		0.110		
L1	1.27		1.40	0.049		0.055		
L2	1.30		1.75	0.050		0.069		
R		0.40			0.015			
V2	0°		8°	0°		8°		

Table 4. D²PAK package mechanical data

Figure 8. D²PAK recommended footprint (dimensions are in mm)





3 Ordering information

Order code	Marking	Package Weight		Base qty.	Delivery mode
FERD60H100CGY-TR	FD60H100CGY	D ² PAK	1.38 g	1000	Tape and reel

Revision history

Table 6. Document revision history

Date	Revision	Changes	
25-Mar-2021	1	First issue.	
06-Apr-2021	2	Updated Features and Applications.	

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